

10.0A Low VF Surface Mount Schottky Barrier Rectifiers-45V

Primary characteristics						
Parameter	Symbol	Value	Unit			
Peak Forward Surge Current	I _{FSM}	275	Α			
Max. Reverse Current (V_R =45V, T_J =25°C)	I _R	0.5	mA			
Repetitive Peak Reverse Voltage	V_{RRM}	45	٧			
Forward Voltage (I _F =8A, T _J =25°C)	VF	0.4	V			

Features

- Ultra Low Forward Voltage Drop
- Very low profile-typical Height of 1.10mm
- Low Power Losses, High Efficiency Operation
- Low Thermal Resistance Package
- High Operating Junction Temperature

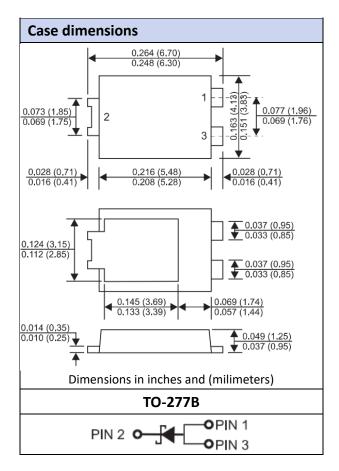
Mechanical data

• Epoxy: UL94-V0 rated flame retardant

Case: TO-277, molded plastic

• Terminals: Solderable per MIL-STD-750, Method 2026

Marking: SB1045L

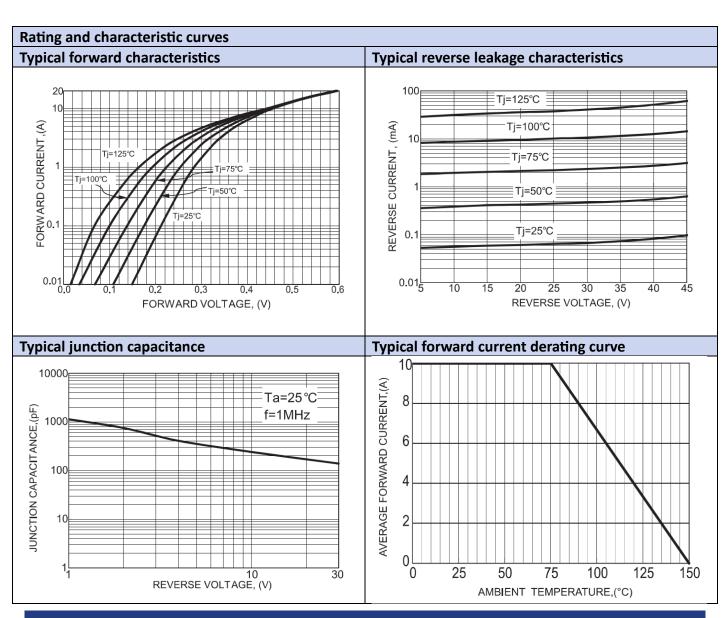


Maximum ratings (T _A = 25°C	Test condition	Symbol	Value			
			Min.	Тур.	Max.	Unit
DC Blocking Voltage		V _{DC}				
Working Peak Reverse Voltage	-	V _{RWM}	-	45	-	V
Repetitive Peak Reverse Voltage		V _{RRM}				
RMS Reverse Voltage	-	V _{RMS}	-	31.5	-	V
Average Forward Rectified Current	-	I _{F(AV)}	-	10.0	-	А
Peak Forward Surge Current, 8.3ms Half Sine-wave (T _A =25 °C)	-	I _{FSM}	-	275	-	А
Operating Junction Temperature Range	-	Tı	-55	-	150	°C
Storage Temperature Range	-	T _{STG}	-55	-	150	°C
Electrical characteristics (T _A	= 25°C, unless otherwise noted)					
Reverse Breakdown Voltage	I _R =0.5mA, T _J =25°C	V _B	45	-	-	V
Forward Voltage	I _F =8A, T _J =25°C	V _F	-	0.40	-	V



	I _F =10A, T _J =25°C		-	0.42	0.47	
	V _R =45V, T _J =25°C		-	0.051	0.5	
Reverse Current	V _R =45V, T _J =100°C	I _R	-	5	15	mA
	V _R =45V, T _J =150°C		-	27	75	
Thermal Characteristics						
Typical thermal resistance junction to ambient ¹⁾	-	R _{θJA}	1	73	1	9 <i>C</i> /\\\
Typical thermal resistance junction to ambient ²⁾	-		-	31	-	°C/W

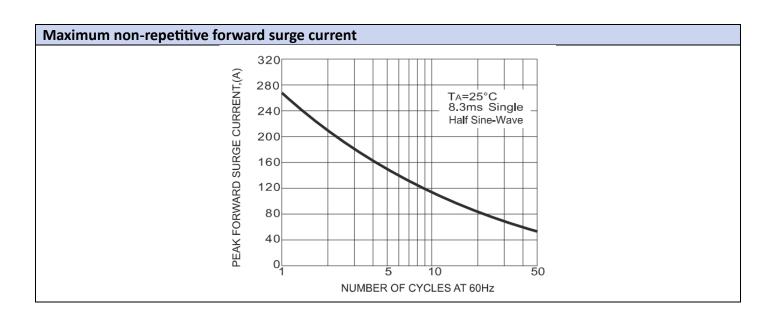
Notes:

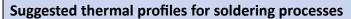


¹⁾ FR-4 PCB, 2oz. Copper

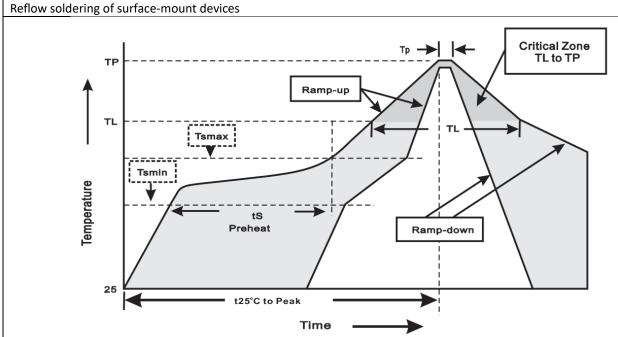
²⁾ Polymide PCB, 2oz. Copper. Cathode pad dimensions 18.8mm x 14.4mm. Anode pad dimensions 5.6mm x 14.4mm







Storage environment: Temperature=5°C \sim 40°C, Humidity=55% \pm 25%



Reflow soldering					
Profile Feature		Soldering Condition	Unit		
Average ramp-up rate (T _L to	T _P)	<3	°C/sec		
Preheat	Temperature min (T _{smin)}	150	°C		
	Temperature max (T _{smax})	200	°C		
	Time (min to max) (t _s)	60~120	sec		
T _{smax} to T _L	Ramp-up rate	<3	°C/sec		
Time maintained above	Temperature (T _L)	217	°C		
	Time (t₁)	60~260	sec		



Peak Temperature (T _P)	255+5	°C
Time within 5 °C of actual Peak Temperature (t _P)	10~30	sec
Ramp-down rate	<6	°C/sec
Time 25 °C to Peak Temperature	<6	minutes

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